

# **2PB709ART** 45 V, 100 mA PNP general-purpose transistor Rev. 01 — 19 March 2007

**Product data sheet** 

## 1. Product profile

### 1.1 General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: 2PD601ART.

### **1.2 Features**

- General-purpose transistor
- Small SMD plastic package

### 1.3 Applications

General-purpose switching and amplification

### 1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-45	V
I <sub>C</sub>	collector current		-	-	-100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -10 \text{ V};$ $I_{C} = -2 \text{ mA}$	210	-	340	

## 2. Pinning information

	Simplified outline	Symbol
base		
emitter		3
collector		
	emitter	emitter



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## 3. Ordering information

Table 3. Order	Ordering information						
Type number	Package						
	Name	Description	Version				
2PB709ART	-	plastic surface-mounted package; 3 leads	SOT23				

## 4. Marking

Table 4. Markir	ng codes	
Type number	Marking code <sup>[1]</sup>	
2PB709ART	C5*	

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

## 5. Limiting values

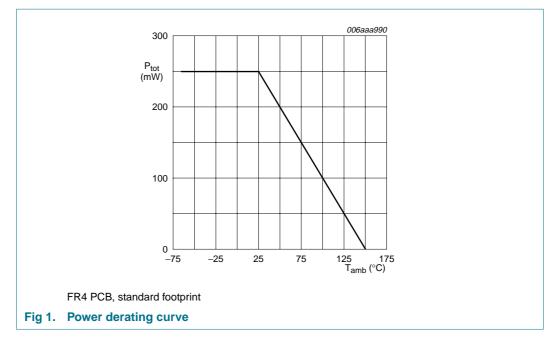
#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0 9 (	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-45	V
$V_{CEO}$	collector-emitter voltage	open base	-	-45	V
$V_{\text{EBO}}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-200	mA
I <sub>BM</sub>	peak base current	single pulse; $t_p \leq 1 \text{ ms}$	-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> _	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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## 6. Thermal characteristics

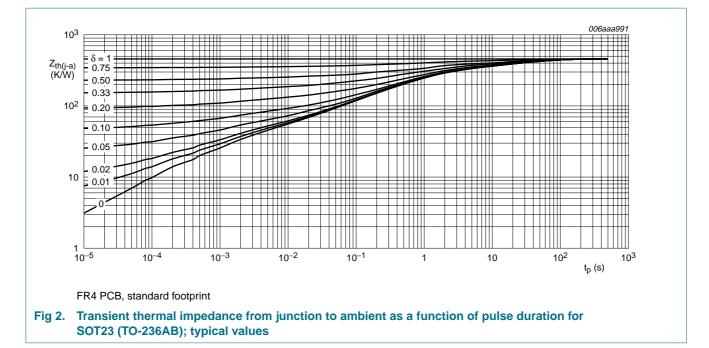
Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	-	140	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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## 7. Characteristics

#### Table 7.Characteristics

 $T_{amb} = 25 \circ C$  unless otherwise specified.

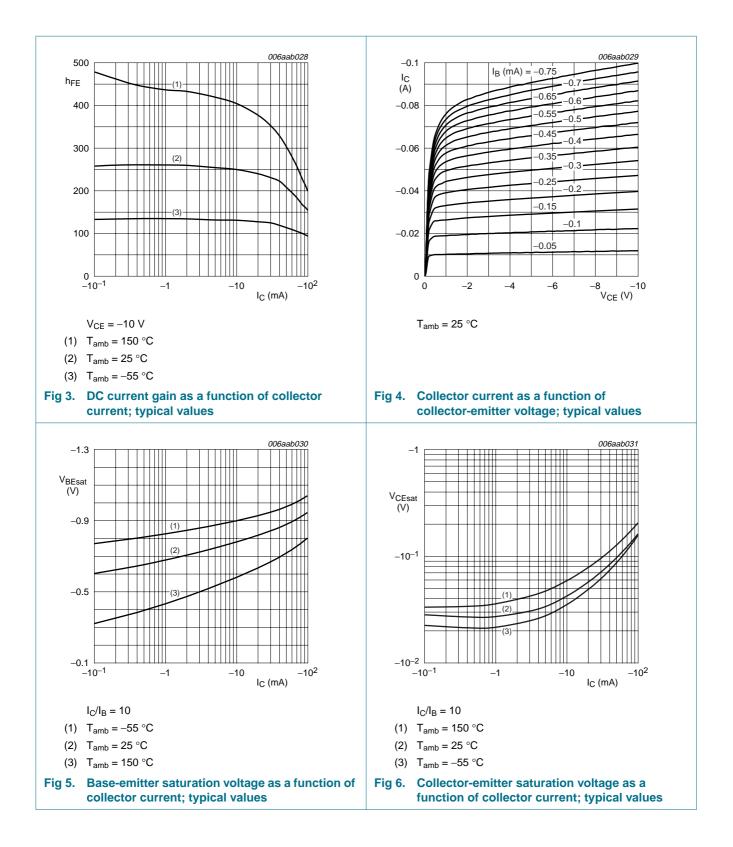
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -45 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	-10	nA
	current	$V_{CB} = -45 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-10	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -10 \text{ V};$ $I_C = -2 \text{ mA}$		210	-	340	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -100 \text{ mA};$ $I_{\rm B} = -10 \text{ mA}$	<u>[1]</u>	-	-	-500	mV
f <sub>T</sub>	transition frequency	$V_{CE} = -10 V;$ $I_{C} = -1 mA;$ f = 100 MHz		70	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ f = 1  MHz		-	-	5	pF

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

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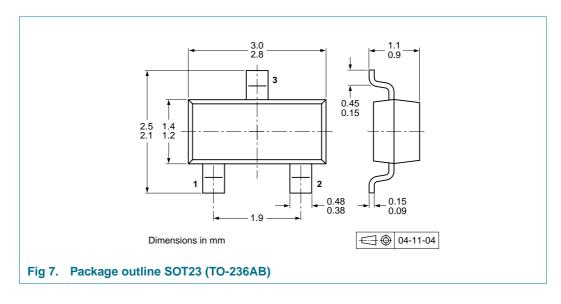
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## 8. Package outline



# 9. Packing information

#### Table 8. Packing methods

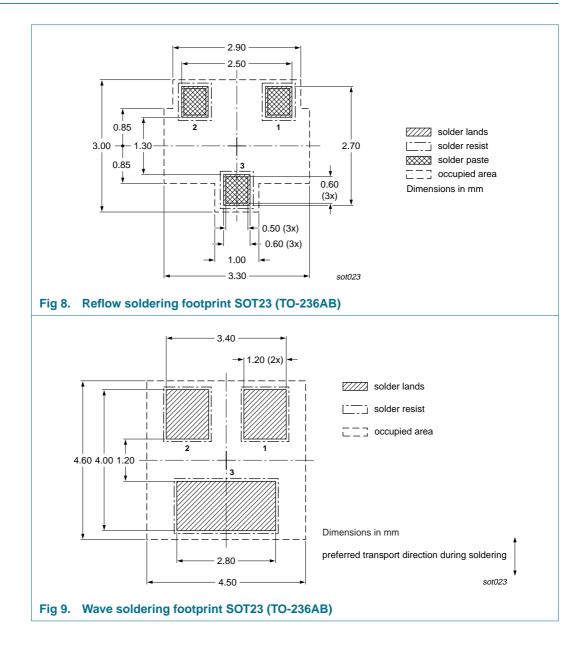
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qu	Packing quantity	
			3000	10000	
2PB709ART	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235	

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

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## **10. Soldering**



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## **11. Revision history**

Table 9. Revision h	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
2PB709ART_1	20070319	Product data sheet	-	-			

#### 45 V, 100 mA PNP general-purpose transistor

## **12. Legal information**

### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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